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BLL8H1214L-250; BLL8H1214LS-250 LDMOS L-band radar power transistor Rev. 3 — 1 September 2015

AMPLEON

Product data sheet

Product profile 1.

1.1 General description

250 W LDMOS power transistor intended for L-band radar applications in the 1.2 GHz to 1.4 GHz range.

Test information Table 1.

Typical RF performance at T_{case} = 25 °C; t_p = 300 μ s; δ = 10 %; I_{Da} = 100 mA; in a class-AB production test circuit.

Test signal	f	V _{DS}	P_L	Gp	η_D	t _r	t _f
	(GHz)	(V)	(W)	(dB)	(%)	(ns)	(ns)
pulsed RF	1.2 to 1.4	50	250	17	55	15	5

1.2 Features and benefits

- Easy power control
- Integrated dual side ESD protection
- High flexibility with respect to pulse formats
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (1.2 GHz to 1.4 GHz)
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding restriction of hazardous substances (RoHS)

1.3 Applications

 L-band power amplifiers for radar applications in the 1.2 GHz to 1.4 GHz frequency range

2. Pinning information

Table 2. Pinning

		Simplified outline	Graphic symbol
214L-250 (SOT502A)			
drain			_
gate			ئے ا
source	<u>[1]</u>		2 —
			3 sym112
214LS-250 (SOT502B)			3,
drain			
gate			1
source	<u>[1]</u>	2	2
			3 sym112
	drain gate source 214LS-250 (SOT502B) drain gate	drain gate source 11 214LS-250 (SOT502B) drain gate	drain gate source [1] 214LS-250 (SOT502B) drain gate source [1] 1 3

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Packag	Package			
	Name	Description	Version		
BLL8H1214L-250	-	flanged ceramic package; 2 mounting holes; 2 leads	SOT502A		
BLL8H1214LS-250	-	earless flanged ceramic package; 2 leads	SOT502B		

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	100	V
V_{GS}	gate-source voltage		-6	+13	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature	[1]	-	225	°C

^[1] Continuous use at maximum temperature will affect the reliability, for details refer to the on-line MTF calculator.

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
Z _{th(j-c)}	transient thermal impedance from	T _{case} = 85 °C; P _L = 250 W		
	junction to case	t_p = 100 μ s; δ = 10 %	0.10	K/W
		t_p = 200 μ s; δ = 10 %	0.13	K/W
		t_p = 300 μ s; δ = 10 %	0.15	K/W
		t_p = 100 μ s; δ = 20 %	0.14	K/W
		t_p = 500 μ s; δ = 20 %	0.20	K/W

6. Characteristics

Table 6. DC characteristics

 $T_i = 25 \, ^{\circ}C$.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 2.7 \text{ mA}$	100	-	-	V
V _{GS(th)}	gate-source threshold voltage	V _{DS} = 10 V; I _D = 270 mA	1.3	1.8	2.25	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 50 V	-	-	1.4	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 V;$ $V_{DS} = 10 V$	32	42	-	A
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	140	nA
9 _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 270 mA	1.6	2.3	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 9.5 \text{ A}$	-	100	169	mΩ

Table 7. RF characteristics

Test signal: pulsed RF; t_p = 300 μ s; δ = 10 %; RF performance at V_{DS} = 50 V; I_{Dq} = 100 mA; T_{case} = 25 °C; unless otherwise specified, in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DS}	drain-source voltage	P _L = 250 W	-	-	50	V
Gp	power gain	P _L = 250 W	15	17	-	dB
RLin	input return loss	P _L = 250 W	-	-10	-	dB
P _{L(1dB)}	output power at 1 dB gain compression		-	300	-	W
η_{D}	drain efficiency	P _L = 250 W	49	55	-	%
P _{droop(pulse)}	pulse droop power	P _L = 250 W	-	0	0.3	dB
t _r	rise time	P _L = 250 W	-	15	-	ns
t _f	fall time	P _L = 250 W	-	5	-	ns

7. Application information

7.1 Ruggedness in class-AB operation

The BLL8H1214L-250 and BLL8H1214LS-250 are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 50 V; I_{Dq} = 100 mA; P_L = 250 W; I_p = 300 μ s; δ = 10 %.

7.2 Impedance information

Table 8. Typical impedance

Typical values unless otherwise specified.

f	Z _S	Z _L
(GHz)	(Ω)	(Ω)
1.2	1.268 – j2.623	2.987 – j1.664
1.3	2.193 – j2.457	2.162 – j1.326
1.4	2.359 – j2.052	1.604 – j1.887

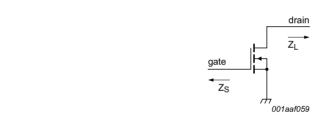


Fig 1. Definition of transistor impedance

7.3 Application circuit

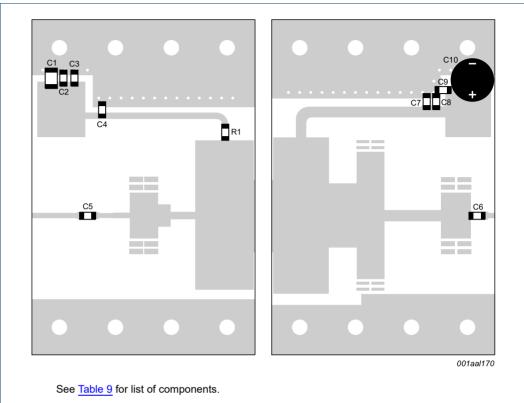


Fig 2. Component layout for class-AB application circuit

Table 9. List of components

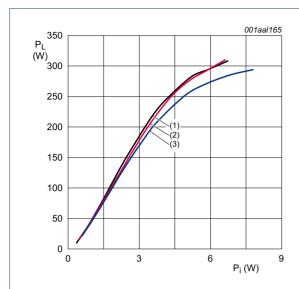
See Figure 2.

Striplines are on a Rogers Duroid 6006 Printed-Circuit Board (PCB); ε_r = 6.15 F/m; thickness = 0.64 mm

Component	Description	Value	Remarks
C1	multilayer ceramic chip capacitor	10 μF, 35 V [1]	
C2, C4	multilayer ceramic chip capacitor	51 pF [2]	
C3, C8	multilayer ceramic chip capacitor	1 nF [2]	
C5	multilayer ceramic chip capacitor	82 pF [3]	
C6, C7	multilayer ceramic chip capacitor	56 pF [3]	
C9	multilayer ceramic chip capacitor	100 pF [3]	
C10	electrolytic capacitor	47 μF, 63 V	
R1	SMD resistor	10 Ω	SMD 0603

- [1] American Technical Ceramics type 100A or capacitor of same quality.
- [2] American Technical Ceramics type 100B or capacitor of same quality.
- [3] American Technical Ceramics type 800B or capacitor of same quality.

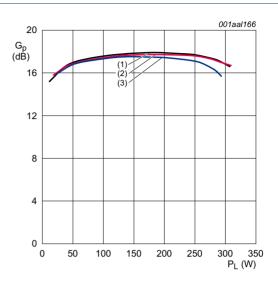
7.4 RF performance graphs



 V_{DS} = 50 V; t_p = 300 $\mu s;~\delta$ = 10 %; I_{Dq} = 100 mA.

- (1) f = 1200 MHz
- (2) f = 1300 MHz
- (3) f = 1400 MHz

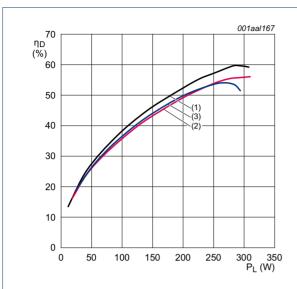
Fig 3. Output power as a function of input power; typical values



 V_{DS} = 50 V; t_p = 300 $\mu s;$ δ = 10 %; I_{Dq} = 100 mA.

- (1) f = 1200 MHz
- (2) f = 1300 MHz
- (3) f = 1400 MHz

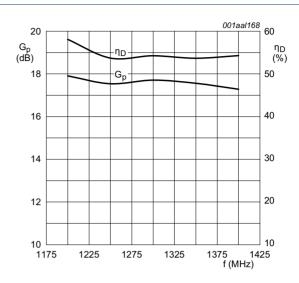
Fig 4. Power gain as a function of output power; typical values



 V_{DS} = 50 V; t_p = 300 μs ; δ = 10 %; I_{Dq} = 100 mA.

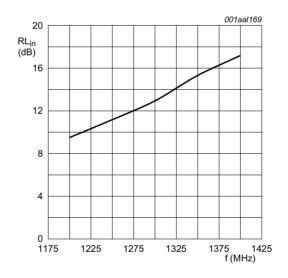
- (1) f = 1200 MHz
- (2) f = 1300 MHz
- (3) f = 1400 MHz

Fig 5. Drain efficiency as a function of output power; typical values



 P_L = 250 W; V_{DS} = 50 V; t_p = 300 $\mu s;$ δ = 10 %; I_{Dq} = 100 mA.

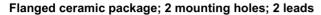
Fig 6. Power gain and drain efficiency as function of frequency; typical values



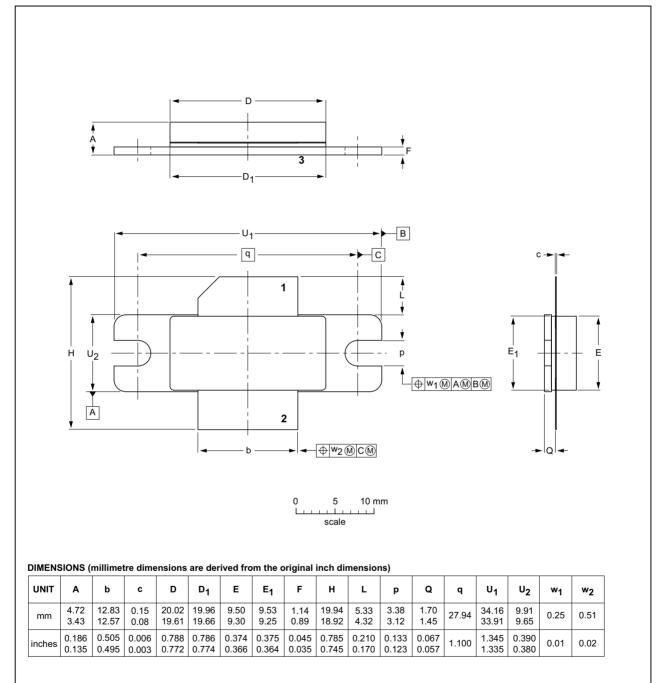
 P_L = 250 W; V_{DS} = 50 V; t_p = 300 $\mu s;$ δ = 10 %; I_{Dq} = 100 mA.

Fig 7. Input return loss as a function of frequency; typical value

Package outline



SOT502A



IEC **JEDEC** JEITA 03-01-10 SOT502A 12-05-02

REFERENCES

Package outline SOT502A Fig 8.

OUTLINE

VERSION

ISSUE DATE

EUROPEAN

PROJECTION

Earless flanged ceramic package; 2 leads

SOT502B

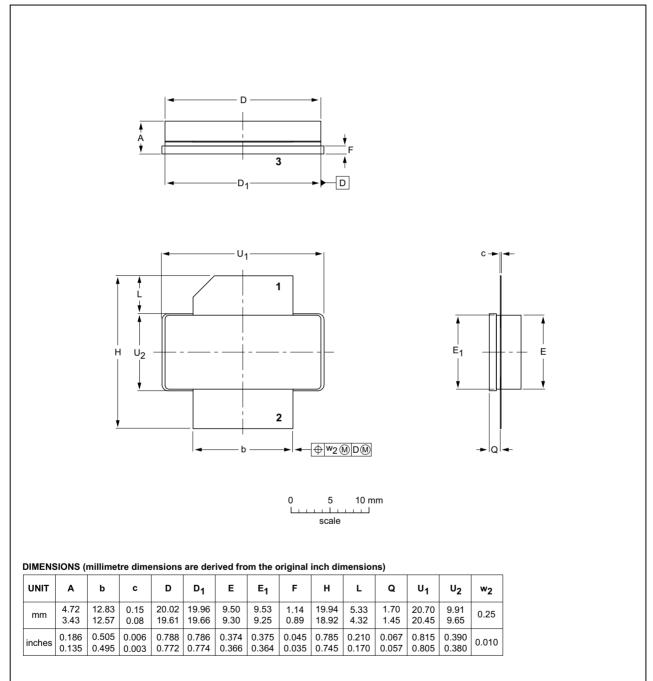


Fig 9. Package outline SOT502B

IEC

OUTLINE

VERSION

SOT502B

JEITA

REFERENCES

JEDEC

ISSUE DATE

07-05-09

12-05-02

EUROPEAN

PROJECTION

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

10. Abbreviations

Table 10. Abbreviations

Acronym	Description	
ESD	lectroStatic Discharge	
L-band	ong wave Band	
LDMOS	aterally Diffused Metal-Oxide Semiconductor	
MTF	Median Time to Failure	
SMD	Surface Mounted Device	
VSWR	Voltage Standing-Wave Ratio	

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLL8H1214L-250_1214LS-250#3	20150901	Product data sheet	-	BLL8H1214L-250_1214LS-250 #2	
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. Legal texts have been adapted to the new company name where appropriate. 				
BLL8H1214L-250_1214LS-250 #2	20150113	Product data sheet	-	BLL8H1214L-250_1214LS-250 #1	
BLL8H1214L-250_1214LS-250 #1	20140930	Objective data sheet	-	-	

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition	
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.	
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.	
Product [short] data sheet	Production	This document contains the product specification.	

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BLL8H1214L(S)-250

LDMOS L-band radar power transistor

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BLL8H1214L(S)-250

LDMOS L-band radar power transistor

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